

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

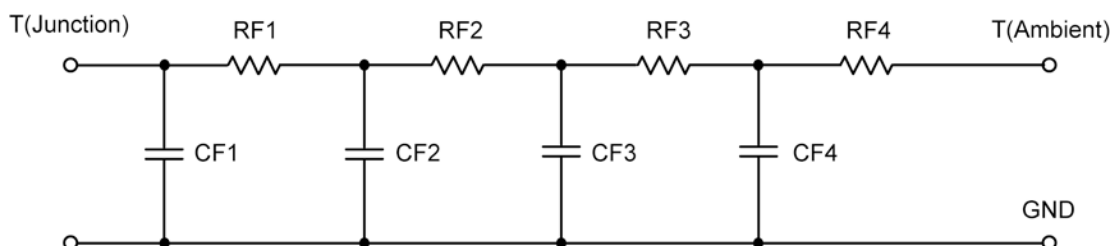
For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	5.6429	N/A	1.7981
RT2	9.1819	N/A	8.3861
RT3	26.3958	N/A	2.8307
RT4	53.7794	N/A	10.9851
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	712.3648 u	N/A	370.7541 u
CT2	21.5506 m	N/A	12.1387 m
CT3	53.1312 m	N/A	2.8770 m
CT4	1.1873	N/A	128.6109 m

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance ($^{\circ}\text{C}/\text{W}$)			
Junction to	Ambient	Case	Foot
RF1	6.6819	N/A	3.5216
RF2	17.4443	N/A	6.2612
RF3	19.8009	N/A	6.1328
RF4	51.0729	N/A	8.0844
Thermal Capacitance (Joules/ $^{\circ}\text{C}$)			
Junction to	Ambient	Case	Foot
CF1	757.5251 u	N/A	443.8253 u
CF2	16.9792 m	N/A	5.3715 m
CF3	46.7434 m	N/A	18.5880 m
CF4	1.1917	N/A	164.4405 m

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya, IEEE / SEMITHERM 2002

